

HS62-5000A-E4 SERIES CURRENT SENSOR/TRANSDUCER

DESCRIPTION:

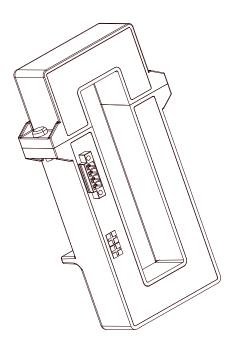
For the electronic measurement of current: DC, AC, pulsed ..., with galvanic separation between the primary and the secondary circuit.

FEATURES:

- ◆ Open loop using the Hall effect
- ◆ The primary side and the secondary side are isolated
- ◆ Low power consumption
- ♦ Wide range
- ♦ No insertion loss
- ◆ Raw materials recognized according to UL 94-V0

APPLICATIONS:

- **♦** Inverter
- ◆ Uninterruptible Power Supplies (UPS)
- ◆ Static converters for DC motor drives
- ◆ Switched Mode Power Supplies (SMPS)
- Power supplies for welding applications
- ♦ Battery management



MODEL LIST:

PRODUCT MODEL					
Model	Rated input current I _{PN} (A)	Measuring range I _{PM} (A)			
HS62-5000A-E4	5000	± 6000			



HS62-A-E4 SPECIFICATION

Parameter	Symbol	Unit	Value	Test Conditions				
Electrical Data								
Supply voltage (±5%) (1)	$V_{\rm C}$	V	±15					
Current consumption	I_{C}	mA	±25					
Output voltage (analog output)	$V_{ m OUT}$	mV	±5V±50	$\underline{\hat{w}} \pm I_{PN}, R_L = 10 \text{ k}\Omega, T_A = 25^{\circ}\text{C}$				
Output clamp voltage	Vmax	V	8.5V	$\underline{@} \pm I_{PM}, R_L = 10 \text{ k}\Omega, T_A = 25^{\circ}\text{C}$				
Overcurrent capability (1ms)	I_{PC}	At	5* I _{PN}					
Insulation resistance	$R_{\rm IS}$	ΜΩ	>1000	@ 500 VDC				
Internal impedance	R _{OUT}	Ω	100	approximation				
Load Resistor (2)	$R_{\rm L}$	ΚΩ	>10					
	Pe	erformance	Data					
Linearity (3) (0± I _{PN})	$\epsilon_{ m L}$	%of I _{PN}	<±0.5					
Precision	X	%	<±1	@ I_{PN} , $T_A = 25^{\circ}C$				
		70		(remove zero offset voltage)				
Zero offset voltage	V_{OE}	mV	<±20	$@ T_A = 25^{\circ}C$				
Magnetic offset voltage	$ m V_{OM}$	mV	<±10	@ I _P =0;				
Wagnetie offset voltage	VOM	111 V	<u> </u>	1 times the rated current impact				
Zero offset temperature drift	TCV_{OE}	mV/K	<±0.5	@ HS62-A- E4				
Output offset temperature drift	TCV _{OUT}	ppm/K	<500	@% of reading				
Response time	t _r	μS	<3	@ 90% of I _{PN} step response				
Current follows d _i /d _t	d_{i}/d_{t}	A/μS	>500					
Bandwidth (4)	BW	kHz	DC~40	@-3dB				
General Data								
Ambient operating temperature	T _A	°C	-40+85					
Ambient storage temperature	Ts	°C	-40+105					
Mass	m	g	-	approximation				



Notice:

- (1) Under the power supply condition of $\pm 12V \le VC \le \pm 15V$, the measurement range of the sensor will be reduced;
- (2) If the customer uses a load resistance of 1 K Ω , the current to be measured needs to be limited to the rated current. If the full-scale current is to be measured, the load resistance should be at least 10 K Ω .
- (3) Linearity data does not include zero offset;

Insulation data:

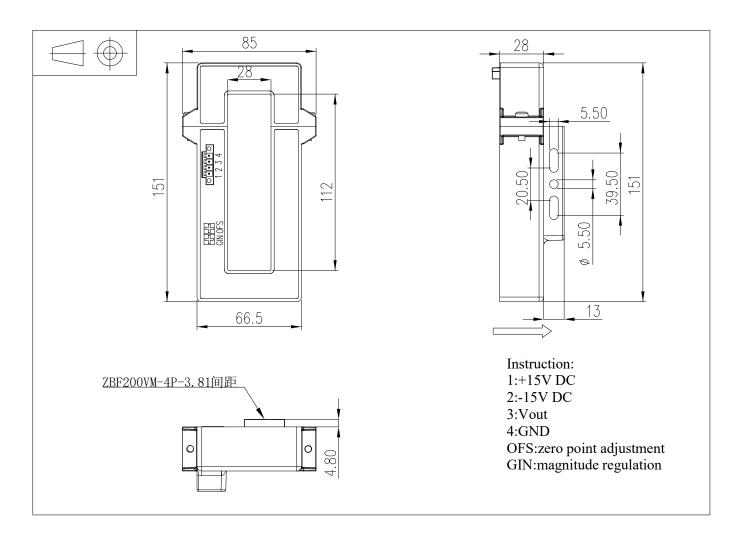
Parameter	Symbol	Unit	Value	Remark
AC isolation withstand voltage test RMS @ 50Hz, 1min	U_D	KV	3	
Impulse withstand voltage 1.2/50uS	U_{W}	KV	12	
Shell material	-	-	UL94-V0	PTE+30%GF
Relative tracking index	CTI	PLC	3	
Creepage distance	d_{CP}	mm	17	
Electrical clearance	d_{CI}	mm	12	

Maximum limit:

Parameter	Symbol	Unit	Value
Supply voltage	V_{C}	V	±18
Output current (output shorted to ground)	$I_{ m out}$	mA	-
Electrostatic discharge - contact discharge	$V_{ m ESD}$	V	-



Mechanical Dimensions:



Safety

This device must be used according to IEC610101.



This device must be used in electric/electronic equipment with respect to applicable standards and safety requirements in accordance with the operating instructions.

Caution, risk of electrical shock.



When operating the device, certain parts can carry hazardous voltage (eg. primary busbar, power supply). Ignoring this warning can lead to injury and/or cause serious damage.

This is a builtin device, whose conducting parts must be inaccessible after installation.

A protective housing or additional shield can be used.

Main supply must be able to be disconnected.